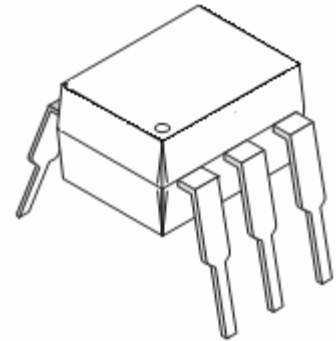


High Reliability Photo Coupler

Features

- High current transfer ratio
(CTR: MIN.500% at $I_F=1\text{mA}$, $V_{ce}=2\text{V}$)
- High isolation voltage between input and output
(Viso: 5000Vrms)
- Compact dual-in-line package



QRCTA16P



Applications

- System appliances, measuring instruments
- Industrial robots
- Copies, automatic vending machines
- Signal transmission between circuits of different potentials and impedances
- Telephone sets
- Copiers, facsimiles
- Interface with various power supply circuits, power distribution boards
- Numerical control machines

Absolute Maximum Ratings (Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	IF	50	mA
	Peak forward current	IFM	1	A
	Reverse voltage	VR	6	A
	Power dissipation	PD	70	mW
Output	Collector-emitter voltage	VCEO	30	V
	Collector-base voltage	VCBO	30	V
	Emitter-base voltage	VEBO	6	V
	Collector current	IC	150	mA
	Collector power dissipation	PC	200	mW
Total power dissipation		Ptot	200	mW
Isolation voltage 1 minute		Viso	5000	Vrms
Operating Temperature		Topr	-55 ~ +115	°C
Storage Temperature		Tstg	-55 ~ +125	°C
Soldering temperature 10 second		Tsol	260	°C

Electro-Optical Characteristics (Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Condition
Input	Forward Voltage	VF	----	1.2	1.4	V	IF =10mA
	Peak forward voltage	VFM	----	----	3.5	V	IFM =0.5A
	Reverse current	IR	----	----	10	uA	VR =4V
	Terminal capacitance	Ct	----	30	----	pF	V =0, f =1kHz
Output	Collector dark current	ICEO	----	----	0.1	uA	VCE =10V, IF =0
Transfer Characteristics	Current transfer ratio	CTR	500	4000	----	%	IF =1mA, VCE =2V
	Collector-emitter saturation voltage	VCE(sat)	----	----	1.0	V	IF =8mA, IC =2mA
	Isolation resistance	Riso	5x10 ¹⁰	----	----	ohm	DC500V
	Floating capacitance	Cf	----	0.6	1.0	pF	V =0, f =1MHz
	Cut-off frequency	fc	----	7	----	kHz	VCC=5V, IC =2mA, RL=100ohm
	Response time (Rise)	tr	----	5	40	us	VCE=10V, IC =50mA RL=100ohm
Response time (Fall)	tf	----	60	100	us		

Typical Electro-Optical Characteristics Curves

Fig.1 Current Transfer Ratio vs. Forward Current

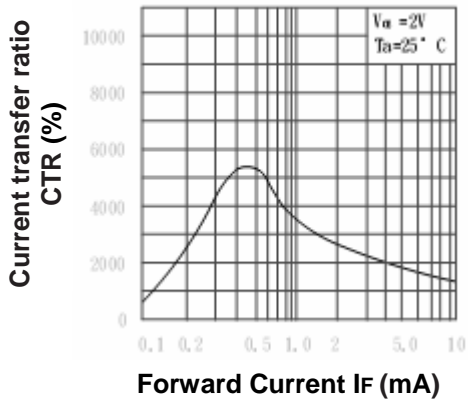


Fig.2 Collector Power Dissipation vs. Ambient Temperature

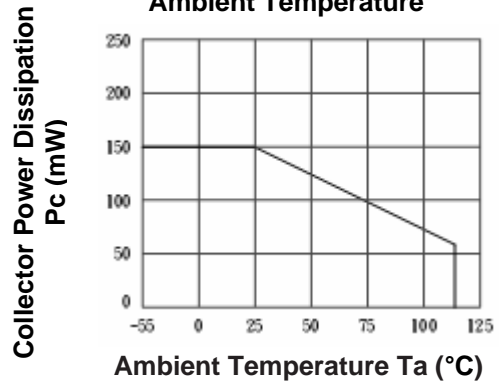


Fig.3 Collector Dark Current vs. Ambient Temperature

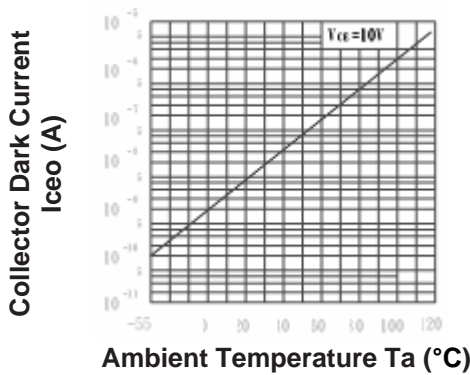


Fig.4 Forward Current vs. Ambient Temperature

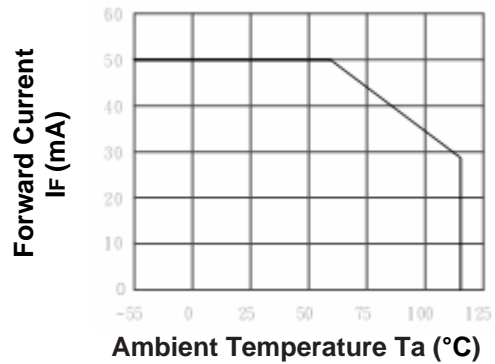


Fig.5 Forward Current vs. Forward Voltage

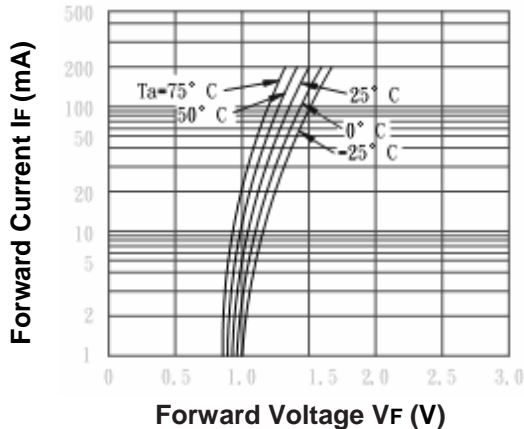


Fig.6 Collector Current vs. Collector Emitter Voltage

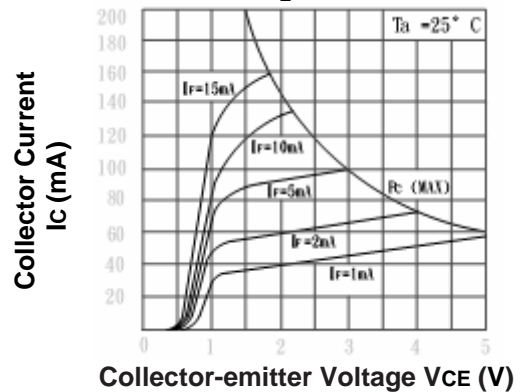


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

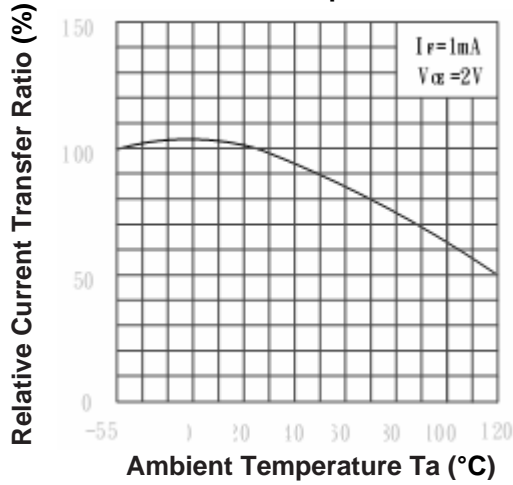


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

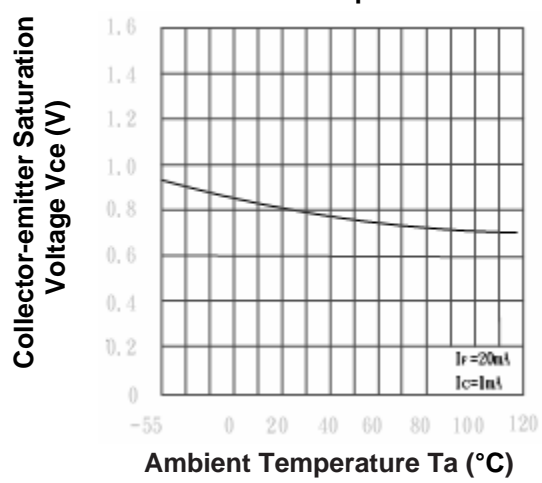


Fig.9 Collector-emitter Saturation Voltage vs. Forward Current

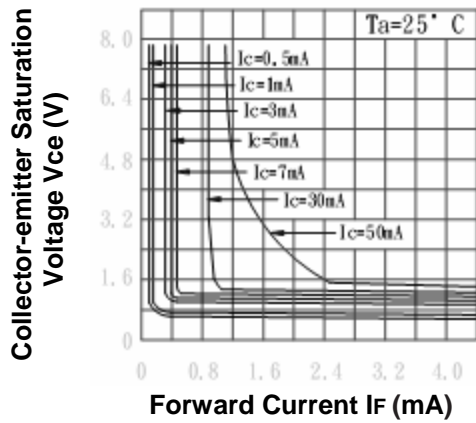


Fig.10 Response Time vs. Load Resistance

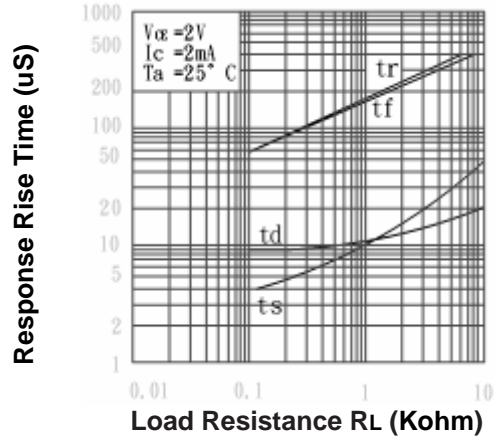
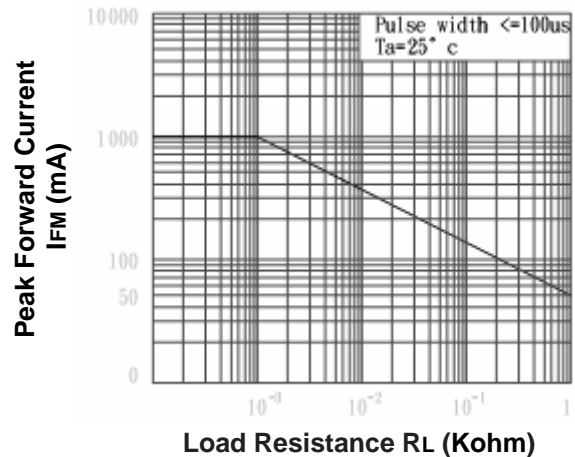
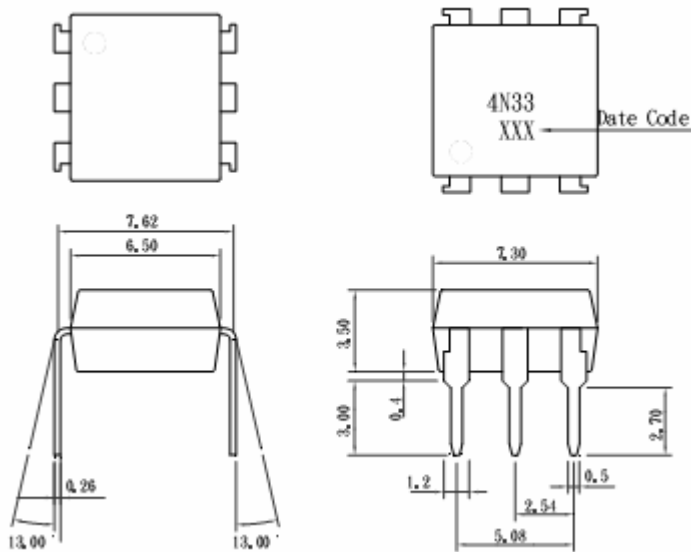


Fig.11 Peak Forward Current vs. Duty Ratio



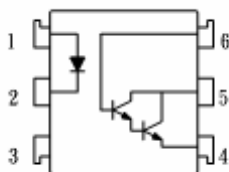
KPC4N33

Package Dimensions (In mm)



Note: 1. Dimensions are in millimeters
2. Tolerances unless dimensions $\pm 0.2\text{mm}$

Schematic: Top View



- 1. Anode
- 2. Cathode
- 3. NC
- 4. Emitter
- 5. Collector
- 6. Base

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